16-bit Universal Bus Driver with 3-state Outputs

HITACHI

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Description

This HD74ALVCF16334 is a 16-bit universal bus driver is designed for 2.3 V to 3.6 V V_{CC} operation.

Data flow from A to Y is controlled by the output enable (\overline{OE}) input. The device operates in the transparent mode when the latch enable (\overline{LE}) input is low. When \overline{LE} is high, the A data is latched if the clock (CLK) input is held at a high or low logic level. If \overline{LE} is high, the A data is stored in the latch/flip flop on the low to high transition of CLK. When \overline{OE} is high, the outputs are in the high impedance state.

To ensure the high impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current sinking capability of the driver.

Features

- VCC = 2.3 V to 3.6 V
- Typical VOL ground bounce < 0.8 V (@VCC = 3.3 V, Ta = 25°C)
- Typical VOH undershoot $> 2.0 \text{ V } (@\text{VCC} = 3.3 \text{ V}, \text{Ta} = 25^{\circ}\text{C})$
- High output current ± 24 mA (@VCC = 3.0 V)
- t_{pd} (CLK to Y) = 3.5 ns (Max) (@V_{CC} = 3.3±0.3 V, Ta = 0 to 85°C)

Function Table

Inputs		Output Y		
ŌE	LE	CLK	Α	
Н	Х	Х	X	Z
L	L	X	L	L
L	L	X	Н	Н
L	Н	↑	L	L
L	Н	↑	Н	Н
L	Н	L or H	X	Y ₀ *1

H: High level

L : Low level

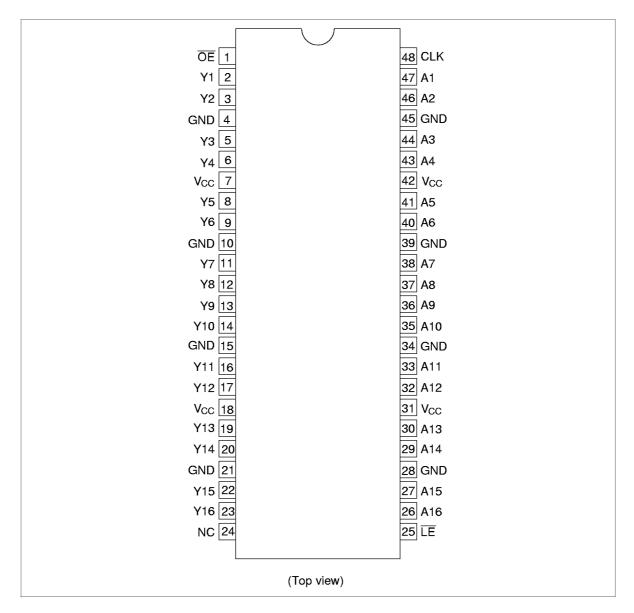
X : Immaterial

Z : High impedance

↑: Low to high transition

Note: 1. Output level before the indicated steady state input conditions were established.

Pin Arrangement



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Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{cc}	-0.5 to 4.6	٧	
Input voltage *1	V _i	-0.5 to 4.6	V	
Output voltage *1, 2	Vo	-0.5 to $V_{\rm cc}$ +0.5	V	
Input clamp current	I _{IK}	-50	mA	V ₁ < 0
Output clamp current	I _{ok}	±50	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$
Continuous output current	Io	±50	mA	$V_{o} = 0$ to V_{cc}
V _{cc} , GND current / pin	I _{CC} or I _{GND}	±100	mA	
Maximum power dissipation at Ta = 55°C (in still air) ³	$P_{\scriptscriptstyle T}$	0.85	W	TSSOP
Storage temperature	T_{stg}	-65 to 150	°C	

Notes:

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

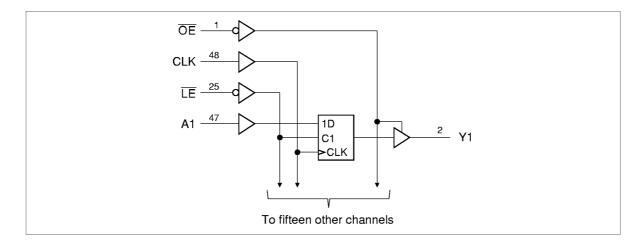
- 1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- 2. This value is limited to 4.6 V maximum.
- 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage	V _{cc}	2.3	3.6	٧	_
Input voltage	V _i	0	V _{cc}	٧	
Output voltage	Vo	0	V _{cc}	٧	
High level output current	I _{OH}	_	-12	mA	V _{cc} = 2.3 V
		_	-12		$V_{cc} = 2.7 \text{ V}$
		_	– 24	_	V _{CC} = 3.0 V
Low level output current	I _{OL}	_	12	mA	V _{cc} = 2.3 V
		_	12		$V_{CC} = 2.7 \text{ V}$
		_	24	_	V _{CC} = 3.0 V
Input transition rise or fall rate	Δt / Δν	0	10	ns / V	
Operating temperature	T _a	-40	85	°C	

Note: Unused control inputs must be held high or low to prevent them from floating.

Logic Diagram



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Electrical Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.3 to 2.7	1.7	_	٧	
		2.7 to 3.6	2.0	_	_	
	V _{IL}	2.3 to 2.7		0.7		
		2.7 to 3.6		8.0	_	
Output voltage	V _{OH}	2.3 to 3.6	V _{cc} -0.2	_	٧	$I_{OH} = -100 \ \mu A$
		2.3	2.0	_		$I_{OH} = -6 \text{ mA}, V_{IH} = 1.7 \text{ V}$
		2.3	1.7	_	_	$I_{OH} = -12 \text{ mA}, V_{IH} = 1.7 \text{ V}$
		2.7	2.2	_	_	$I_{OH} = -12 \text{ mA}, V_{IH} = 2.0 \text{ V}$
		3.0	2.4	_		$I_{OH} = -12 \text{ mA}, V_{IH} = 2.0 \text{ V}$
		3.0	2.0	_	_	$I_{OH} = -24 \text{ mA}, V_{IH} = 2.0 \text{ V}$
	V _{OL}	2.3 to 3.6	_	0.2		$I_{OL} = 100 \mu A$
		2.3	_	0.4		$I_{OL} = 6 \text{ mA}, V_{IL} = 0.7 \text{ V}$
		2.3		0.7	_	$I_{OL} = 12 \text{ mA}, V_{IL} = 0.7 \text{ V}$
		2.7		0.4	_	$I_{OL} = 12 \text{ mA}, V_{IL} = 0.8 \text{ V}$
		3.0	_	0.55		$I_{OL} = 24 \text{ mA}, V_{IL} = 0.8 \text{ V}$
Input current	I _{IN}	3.6		±5	μΑ	V _{IN} = V _{CC} or GND
Off state output current	l _{oz}	3.6		±10	μΑ	$V_{OUT} = V_{CC}$ or GND
Quiescent supply current	t I _{cc}	3.6		40	μΑ	V _{IN} = V _{CC} or GND
	ΔI_{cc}	3.0 to 3.6	_	750	μА	V_{IN} = one input at (V _{CC} -0.6) V, other inputs at V _{CC} or GND

Switching Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	FROM (Input)	TO (Output)
Maximum clock frequency	f _{max}	2.5±0.2	150	_	_	MHz		
		2.7	150	_	_	_		
		3.3±0.3	150	_	_			
Propagation delay time	t _{PLH}	2.5±0.2	1.0	_	3.7	ns	Α	Υ
	t _{PHL}	2.7	_	_	3.6	_		
		3.3±0.3	1.1		3.3			
		2.5±0.2	1.0	_	4.8	_	LE	Υ
		2.7	_		4.4			
		3.3±0.3	1.3	_	4.4			
		2.5±0.2	1.0	_	4.4	_	CLK	Υ
		2.7	_	_	4.1	_		
		3.3±0.3	1.0	_	4.1	_		
Output enable time	t _{zH}	2.5±0.2	1.0	_	5.4	ns	ŌĒ	Υ
	t_{zL}	2.7	_		4.6	_		
		3.3±0.3	1.1		4.6	_		
Output disable time	t _{HZ}	2.5±0.2	1.0	_	4.1	ns	ŌĒ	Υ
	$t_{\scriptscriptstyle LZ}$	2.7	_	_	4.4	_		
		3.3±0.3	1.7	_	4.4	_		
Input capacitance	C _{IN}	3.3	_	5.5	_	рF	Control in	puts
		3.3	_	6.0	_	_	Data inpu	ts
Output capacitance	Co	3.3		8.0		pF	Outputs	

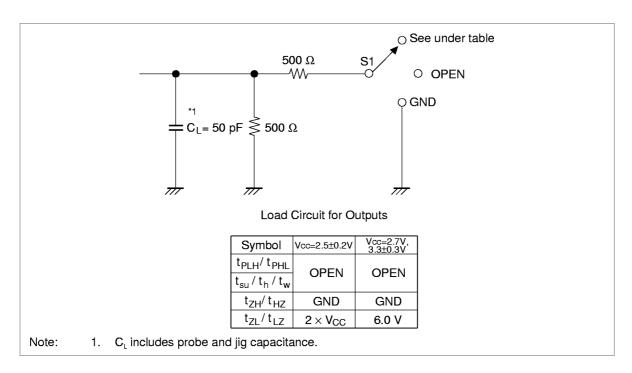
Switching Characteristics (Ta = -40 to 85°C) (cont)

Item	Symbol	$V_{cc}(V)$	Min	Тур	Max	Unit	FROM (Input)
Setup time	t _{su}	2.5±0.2	1.4	_	_	ns	Data before CLK↑
		2.7	1.7	_	_		
		3.3±0.3	1.5	<u>—</u>	_		
		2.5±0.2	1.2	_	_		Data before LE ↑
		2.7	1.6	_	_	_	CLK "H"
		3.3±0.3	1.3	_	_	_	
		2.5±0.2	1.4	_	_		Data before LE ↑
		2.7	1.5	_	_	_	CLK "L"
		3.3±0.3	1.2	_	_	_	
Hold time	t _h	2.5±0.2	0.9	_	_	ns	Data after CLK↑
		2.7	8.0	_	_	_	
		3.3±0.3	0.9	_	_	_	
		2.5±0.2	1.2	_	_		Data after LE ↑
		2.7	1.1	_	_	_	CLK "H" or "L"
		3.3±0.3	1.1	_	_	_	
Pulse width	t _w	2.5±0.2	3.3	_	_	ns	LE "L"
		2.7	3.3	_	_		
		3.3±0.3	3.3	_	_		
		2.5±0.2	3.3	_	_		CLK "H" or "L"
		2.7	3.3	_	_		
		3.3±0.3	3.3	_	_		

Switching Characteristics (Ta = 0 to 85°C)

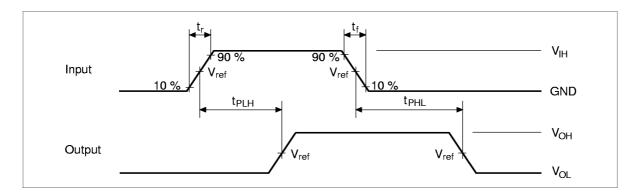
Item	Symbo	IV _{cc} (V)	Min	Тур	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time C _L =50pF	t _{PLH} , t _{PHL}	3.3±0.3	1.4	_	3.5	ns	CLK	Υ
Setup time	t _{su}	3.3±0.3	1.0	_		ns	Data bef	ore CLK↑
Hold time	t _h	3.3±0.3	0.6	_		ns	Data aft	er CLK

Test Circuit

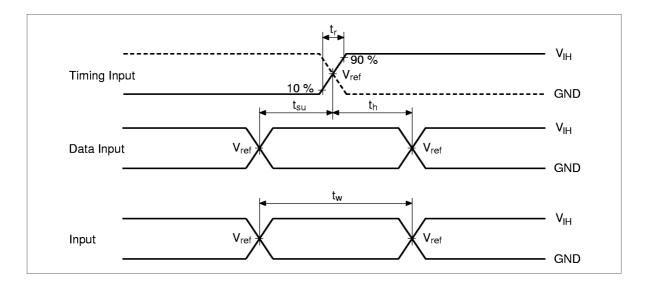


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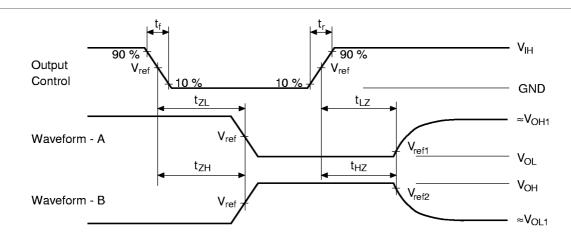
Waveforms – 1



Waveforms - 2



Waveforms - 3

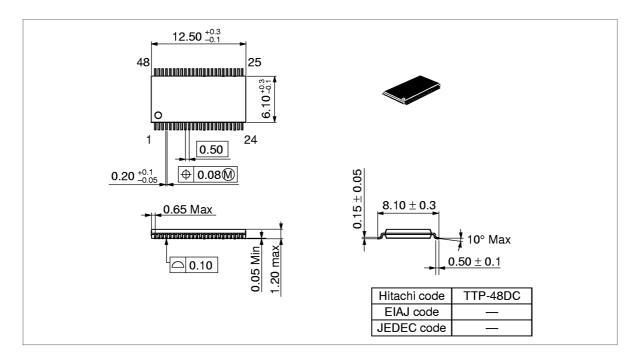


TEST	Vcc=2.5±0.2V	Vcc=2.7V, 3.3±0.3V
V_{IH}	V_{CC}	2.7 V
V_{ref}	1/2 V _{CC}	1.5 V
V _{ref1}	V _{OL} +0.15 V	V _{OL} +0.3 V
V _{ref2}	V _{OH} –0.15 V	V _{OH} -0.3 V
V _{OH1}	V _{CC}	3.0 V
V _{OL1}	GND	GND

Notes:

- 1. All input pulses are supplied by generators having the following characteristics : PRR \leq 10 MHz, Zo = 50 Ω , $t_{_{\!f}} \leq$ 2.0 ns, $t_{_{\!f}} \leq$ 2.0 ns. (V $_{\!\scriptscriptstyle CC}$ = 2.5±0.2 V) PRR \leq 10 MHz, Zo = 50 Ω , $t_{_{\!f}} \leq$ 2.5 ns, $t_{_{\!f}} \leq$ 2.5 ns. (V $_{\!\scriptscriptstyle CC}$ = 2.7 V, 3.3±0.3 V)
- 2. Waveform A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 3. Waveform B is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. The output are measured one at a time with one transition per measurement.

Package Dimensions (Unit: mm)



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IITACHI

Hitachi, Ltd.

Semiconductor & IC Div.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor (America) Inc. 2000 Sierra Point Parkway Brisbane, CA 94005-1897 Tel: <1> (800) 285-1601 Fax: <1> (303) 297-0447

Hitachi Europe GmbH Electronic components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park

Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Towe Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281

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